

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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CMXT2907A

SURFACE MOUNT DUAL PNP SILICON TRANSISTORS



www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMXT2907A type is a dual PNP silicon transistor manufactured by the epitaxial planar process, epoxy molded in a SUPERmini™ surface mount package, and designed for small signal general purpose and switching applications.

MARKING CODE: X2F



MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	VCEO	60	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Continuous Collector Current	īc	600	mA
Power Dissipation	P_{D}	350	mW
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	Θ_{JA}	357	°C/W

EL ECTRICAL	CHARACTERISTICS	DED TRANSISTOR.	· (T • =25°C unlace	otherwice noted)

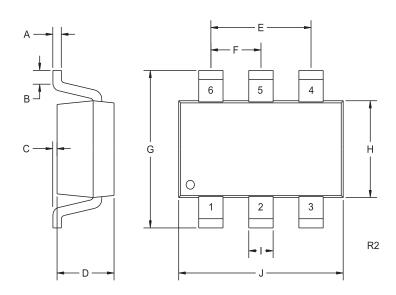
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I _{CBO}	V _{CB} =50V		10	nA
I _{CBO}	V _{CB} =50V, T _A =125°C		10	μΑ
ICEV	V _{CE} =30V, V _{BE} =0.5V		50	nA
BVCBO	I _C =10μA	60		V
BVCEO	I _C =10mA	60		V
BVEBO	I _E =10μA	5.0		V
VCE(SAT)	I _C =150mA, I _B =15mA		0.4	V
VCE(SAT)	I_C =500mA, I_B =50mA		1.6	V
VBE(SAT)	I _C =150mA, I _B =15mA		1.3	V
V _{BE} (SAT)	I _C =500mA, I _B =50mA		2.6	V
h _{FE}	V _{CF} =10V, I _C =0.1mA	75		
hFE	V _{CE} =10V, I _C =1.0mA	100		
h _{FE}	V _{CE} =10V, I _C =10mA	100		
h _{FE}	V _{CE} =10V, I _C =150mA	100	300	
hFE	V _{CE} =10V, I _C =500mA	50		
f _T	V _{CE} =20V, I _C =50mA, f=100MHz	200		MHz
C _{ob}	V _{CB} =10V, I _E =0, f=1.0MHz		8.0	pF
C _{ib}	V _{BE} =2.0V, I _C =0, f=1.0MHz		30	pF
ton	V _{CC} =30V, V _{BE} =0.5V, I _C =150mA, I _{B1} =15mA	45	ns	
t _d	V _{CC} =30V, V _{BE} =0.5V, I _C =150mA, I _{B1} =15mA	10	ns	
tr	V _{CC} =30V, V _{BE} =0.5V, I _C =150mA, I _{B1} =15mA	40	ns	
^t off	V _{CC} =6.0V, I _C =150mA, I _{B1} =I _{B2} =15mA		100	ns
ts	V _{CC} =6.0V, I _C =150mA, I _{B1} =I _{B2} =15mA		80	ns
t_f	V _{CC} =6.0V, I _C =150mA, I _{B1} =I _{B2} =15mA		30	ns

CMXT2907A

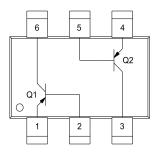
SURFACE MOUNT DUAL PNP SILICON TRANSISTORS



SOT-26 CASE - MECHANICAL OUTLINE



PIN CONFIGURATION



DIMENSIONS					
	INCHES		MILLIMETERS		
SYMBOL	MIN	MAX	MIN	MAX	
Α	0.004	0.007	0.11	0.19	
В	0.016	-	0.40	-	
С	-	0.004	-	0.10	
D	0.039	0.047	1.00	1.20	
E	0.074	0.075	1.88	1.92	
F	0.037	0.038	0.93	0.97	
G	0.102	0.118	2.60	3.00	
Ι	0.059	0.067	1.50	1.70	
	0.016		0.41		
J	0.110	0.118	2.80	3.00	

SOT-26 (REV: R2)

LEAD CODE:

- 1) Emitter Q1
- 2) Base Q1
- 3) Collector Q2 4) Emitter Q2
- 5) Base Q2
- 6) Collector Q1

MARKING CODE: X2F

R3 (12-February 2010)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- · Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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